Plastic Infrared Emitting Diode

OP266AA, OP266AC, OP266AD Obsolete (OP266AB)

Features:

- T-1 (3 mm) package style
- Narrow irradiance pattern
- Dome lens
- Higher power output than GaAs at equivalent drive currents
- 850 nm diode

Description:

Each device in the **OP266AA** series is a high intensity gallium aluminum arsenide infrared emitting diode (GaAIAs) that is molded in an IR transmissive clear or amber-tinted epoxy package with a dome lens. Devices feature a narrow source irradiance pattern and a variety of electrical characteristics. The small T-1 package style makes these devices ideal for space-limited applications.

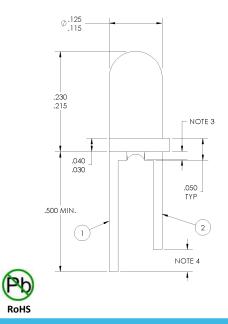
These devices are mechanically and spectrally matched to other OPTEK products as follows:

The OP266AA family conform to the OP506 and OP535 series devices.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

Applications:

- Space-limited applications
- Applications requiring coupling efficiency
- Battery-operated or voltage-limited applications



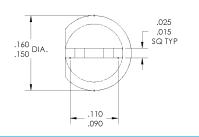
Ordering Information								
Part Number	LED Peak Wavelength	· · · · · · · · · · · · · · · · · · ·		Total Beam Angle	Lead Length			
OP266AA		5.5 / NA		18°	MIN 0.100"			
OP266AB (Obsolete)	850 nm	7.5 / 12.5	20 / 50					
OP266AC		11.5 / 16.5	,					
OP266AD		15.5 / NA						

NOTES:

- 1. Outside discrete shell is polysulfone <u>CLEAR</u>.
- 2. This LED is built with a GaAlAs chip.
- Max allowable epoxy miniscus is 0.030".
 For identification purposes. Cathode lead is 06

 For identification purposes, Cathode lead is .065" ± .035" longer than the anode lead.

5. Dimensions are in inches.



-			
Pin #	LED Cathode		
1			
2	Anode		

1

CONTAINS POLYSULFONE To avoid stress cracking, we suggest using ND Industries' Vibra-Tite for thread-locking. Vibra-Tite evaporates fast without causing structural failure in

OPTEK'S molded plastics

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

TT Electronics | OPTEK Technology 2900 E. Plano Pkwy, Plano, TX 75074 | Ph: +1 972 323 2200 www.ttelectronics.com | sensors@ttelectronics.com



Plastic Infrared Emitting Diode

OP266AA, OP266AC, OP266AD Obsolete (OP266AB)



Electrical Specifications

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Storage and Operating Temperature Range	-40° C to +100° C
Reverse Voltage	2.0 V
Continuous Forward Current	50 mA
Peak Forward Current (1 μs pulse width, 300 pps)	3.0 A
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260° C ⁽¹⁾
Power Dissipation	100 mW ⁽²⁾

Notes:

1. RMA flux is recommended. Duration can be extended to 10 second maximum when flow soldering. A maximum of 20 grams force may be applied to the leads when soldering.

2. Derate linearly at 1.33 mW/° C above 25° C.

 E_{E(APT)} is a measurement of the average apertured radiant incidence upon a sensing area 0.081" (2.06 mm) in diameter, perpendicular to and centered on the mechanical axis of the lens and 0.590" (14.99 mm) from the measurement surface. E_{E(APT)} is not necessarily uniform within the measured area.

SYMBOL	PARAMETER	MIN	ТҮР	ΜΑΧ	UNITS	TEST CONDITIONS				
Input Diode										
E _{e(apt)}	Apertured Radiant Incidence OP266AA OP266AC OP266AD	5.50 11.50 15.50	- - -	- 16.5 -	mW/cm²	I _F = 20 mA Aperture = 0.081" diameter Distance = 0.590" from seating surface to aperture surface				
V _F	Forward Voltage	-	-	1.80	V	I _F = 20 mA				
I _R	Reverse Current	-	10	-	μΑ	V _R = 10 V				
λ_{P}	Wavelength at Peak Emission	-	850	-	nm	I _F = 10 mA				
$\Delta\lambda_P/\Delta T$	Spectral Shift with Temperature	-	±0.18	-	nm/°C	I _F = Constant				
θ_{HP}	Emission Angle at Half Power Points	-	18	-	Degree	I _F = 20 mA				
t _r	Output Rise Time	-	10	-	ns	I _{F(PK)} = 100 mA, PW = 10 μs, D.C. = 10.0 %				
t _f	Output Fall Time	-	10	-	ns	I _{F(PK)} = 100 mA, PW = 10 μs, D.C. = 10.0 %				

Electrical Characteristics (T_A = 25° C unless otherwise noted)

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

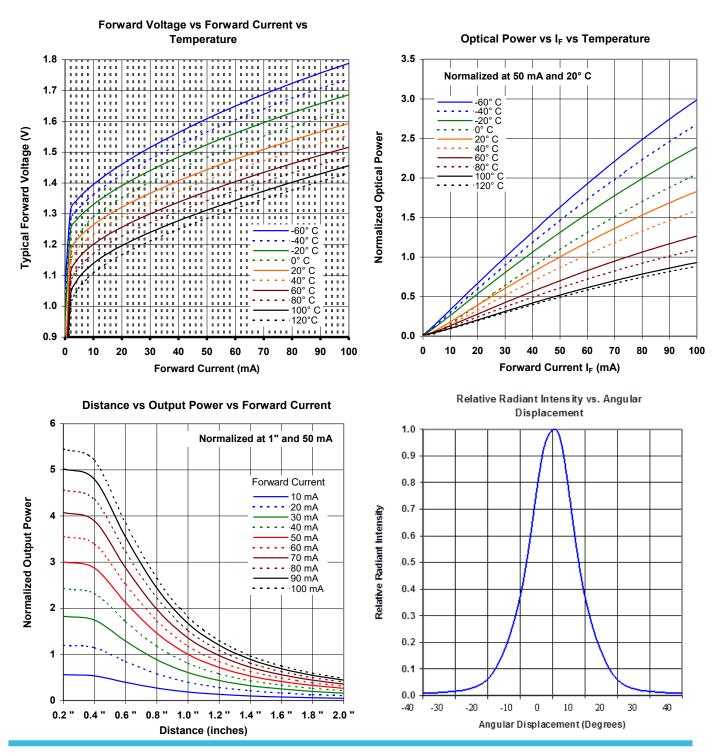
TT Electronics | OPTEK Technology 2900 E. Plano Pkwy, Plano, TX 75074 | Ph: +1 972 323 2200 www.ttelectronics.com | sensors@ttelectronics.com

Plastic Infrared Emitting Diode

OP266AA, OP266AC, OP266AD Obsolete (OP266AB)



Performance OP266AA, AC, AD



General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

TT Electronics | OPTEK Technology 2900 E. Plano Pkwy, Plano, TX 75074 | Ph: +1 972 323 2200 www.ttelectronics.com | sensors@ttelectronics.com